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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO. CONFIRMATION		
10/791,813	03/04/2004	Jung Hoon Seo	1630-0138P 3656		
2292	7590 06/27/2005		EXAMINER		
	WART KOLASCH & BI	MALDONADO, JULIO J			
PO BOX 747 FALLS CHUI	RCH, VA 22040-0747	ART UNIT	PAPER NUMBER		
			2823		
			DATE MAILED: 06/27/2005		

Please find below and/or attached an Office communication concerning this application or proceeding.

		Applicati	on No.	Applicant(s)				
			13	SEO, JUNG HOON				
Office Action Summary		Examine		Art Unit				
		Julio J. M	aldonado	2823				
Period fo	The MAILING DATE of this communication Reply	ion appears on th	cover sheet with the	correspondence ad	idress			
THE - Exte after - If the - If NO - Failt Any	ORTENED STATUTORY PERIOD FOR MAILING DATE OF THIS COMMUNICA' nsions of time may be available under the provisions of 37 SIX (6) MONTHS from the mailing date of this communicate period for reply specified above is less than thirty (30) date of period for reply is specified above, the maximum statutor interest or reply within the set or extended period for reply will, I reply received by the Office later than three months after the patent term adjustment. See 37 CFR 1.704(b).	TION. 'CFR 1.136(a). In no evation. ys, a reply within the stary period will apply and we by statute, cause the app	ent, however, may a reply be til utory minimum of thirty (30) day ill expire SIX (6) MONTHS from dication to become ABANDONE	mely filed ys will be considered time the mailing date of this of the considered time.				
Status								
1)	Responsive to communication(s) filed or	n						
2a) <u></u> ☐								
3)□	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.							
Disposit	ion of Claims							
5) <u>□</u> 6)⊠	 Claim(s) 1-3 is/are pending in the application. 4a) Of the above claim(s) is/are withdrawn from consideration. Claim(s) is/are allowed. Claim(s) 1-3 is/are rejected. Claim(s) is/are objected to. Claim(s) are subject to restriction and/or election requirement. 							
Applicati	on Papers							
·	The specification is objected to by the Ex The drawing(s) filed on is/are: a)[Applicant may not request that any objection	accepted or b						
11)	Replacement drawing sheet(s) including the The oath or declaration is objected to by	correction is requir	ed if the drawing(s) is ob	ojected to. See 37 C	• •			
Priority (ınder 35 U.S.C. § 119		<u>`</u>					
12)⊠ a)i	Acknowledgment is made of a claim for f All b) Some * c) None of: 1. Certified copies of the priority doc 2. Certified copies of the priority doc 3. Copies of the certified copies of the application from the International See the attached detailed Office action for	uments have bee uments have bee ne priority documo Bureau (PCT Rul	en received. en received in Applicat ents have been receive e 17.2(a)).	ion No ed in this National	Stage			
Attachmen	t(s) e of References Cited (PTO-892)		4) Thionious Summan	//PTO 412\				
2) D Notic 3) D Inform	e of References Cited (PTO-692) e of Draftsperson's Patent Drawing Review (PTO-9 nation Disclosure Statement(s) (PTO-1449 or PTO r No(s)/Mail Date		4) Interview Summary Paper No(s)/Mail D 5) Notice of Informal F 6) Other:	ate	O-152)			

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DETAILED ACTION

Drawings

1. Figure 1 should be designated by a legend such as --Prior Art-- because only that which is old is illustrated. See MPEP § 608.02(g). Corrected drawings in compliance with 37 CFR 1.121(d) are required in reply to the Office action to avoid abandonment of the application. The replacement sheet(s) should be labeled "Replacement Sheet" in the page header (as per 37 CFR 1.84(c)) so as not to obstruct any portion of the drawing figures. If the changes are not accepted by the examiner, the applicant will be notified and informed of any required corrective action in the next Office action. The objection to the drawings will not be held in abeyance.

Specification

2. The disclosure is objected to because of the following informalities: in page 2, paragraph [0006], line 3, where applicants cite "...sapphire substrate...activated layer...", should cite --sapphire substrate (10)...activated layer (12)--; in page 7, paragraph [0032], line 3, where applicants cite "...electrode...", should cite --electrode (24)--.

Appropriate correction is required.

Claim Rejections - 35 USC § 103

- 3. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

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4. Claims1-3 are rejected under 35 U.S.C. 103(a) as being unpatentable over the Applicants' Admitted Prior Art in view of Matsumoto et al. (U.S. 2003/0082893 A1).

The prior art (Instant Fig.1) teaches a method of forming a light-emitting device comprising the steps of forming n-GaN layer (11), an activated layer (12) and p-GaN layer (13) on a sapphire substrate (10); mesa-cutting said p-GaN layer (13), said activated layer (12) and part of the n-GaN (11); forming a transparent electrode (14) for extending an electric current on the top of the p-GaN layer (13); and forming an n-pad electrode (15) on top of said n-GaN layer (11) and a p-pad electrode (16) on top of said transparent electrode (14) (Instant pages 1, [0003] – page 2, [0006]). Furthermore, the prior art teaches activating said p-GaN layer (13) by performing a heating process under the condition of oxygen (Instant page 7, [0007]).

The prior art fails to teach wherein said activating of said p-GaN layer is performed under oxygen plasma. However, Matsumoto et al. (Figs.2A-3) teach a method of forming a light-emitting device including the steps of forming n-GaN layer (22), an activated layer (25) and p-GaN layer (28) on a sapphire substrate (21); plasma activating said p-GaN layer (28), wherein said plasma activating is an oxygen plasma; mesa-cutting said p-GaN layer (13), said activated layer (12) and part of the n-GaN (11); and forming an n contact (32) on the n-GaN layer (22) and a p contact (29) on the p-GaN layer ([0017] – [0041]). Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to combine the teachings of the prior art and Matsumoto et al. to enable activating the p-GaN layer of the prior art using

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plasma oxygen as taught by Matsumoto et al., because this would improve the contact resistance of the p-contact with the p-GaN layer ([0004] and [0036]).

Conclusion

5. Any inquiry concerning this communication or earlier communications from the examiner should be directed to examiner Julio J. Maldonado whose telephone number

is (571) 272-1864. The examiner can normally be reached on Monday through Friday.

6. If attempts to reach the examiner by telephone are unsuccessful, the examiner's

supervisor, Olik Chaudhuri, can be reached on (571) 272-1855. The fax number for this

group is 703-872-9306 for before final submissions, 703-872-9306 for after final

submissions and the customer service number for group 2800 is (703) 306-3329.

Updates can be found at http://www.uspto.gov/web/info/2800.htm.

Julio J. Maldonado Patent Examiner Art Unit 2823

Julio J. Maldonado June 22, 2005

George Fourson
Primary Examiner